

IRG8CH76K10F

Request a Quote

IRG8CH76K10F Information

Heisener.com	Part Number	IRG8CH76K10F
	Manufacturer	Infineon Technologies
	Category	Discrete Semiconductor Products Transistors - IGBTs - Single
	Description	IGBT CHIP WAFER
	Package	Die
		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRG8CH76K10F Specifications

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Manufacturer Part Number	IRG8CH76K10F
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	-
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	75A
Current - Collector Pulsed (Icm)	-
Vce(on) (Max) @ Vge, Ic	2V @ 15V, 75A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	480nC
Td (on/off) @ 25°C	80ns/210ns
Test Condition	600V, 75A, 1.5 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-40°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die
	Report errors?

IRG8CH76K10F Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IRG8CH76K10F Payment Methods





If you have any question about IRG8CH76K10F, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com